

Abstract Submitted  
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**Out-of-Equilibrium Dynamics of a Strongly Correlated Electron System in Two Dimensions**<sup>1</sup> DRAGANA POPOVIĆ, National High Magnetic Field Laboratory (NHMFL) and Department of Physics, Florida State University (FSU), JAN JAROSZYŃSKI, NHMFL, FSU — Slow, nonexponential relaxations of conductivity  $\sigma(t)$  have been studied in a strongly disordered two-dimensional electron system (2DES) in Si MOSFETs in the vicinity of the metal-insulator transition (MIT). The 2DES is excited far from equilibrium by a rapid change of carrier density  $n_s$  at low temperatures  $T$ . The dramatic and precise dependence of  $\sigma(t)$  on  $n_s$  and  $T$  shows that (a) the equilibration time diverges exponentially as  $T \rightarrow 0$ , suggesting a glass transition at  $T_g = 0$ , and (b) the Coulomb interactions between 2D electrons play a dominant role in the observed out-of-equilibrium dynamics [1]. The scaling of  $\sigma(t, T)$  is also consistent with  $T_g = 0$ . These results support conclusions based on earlier noise measurements [2] that, in a 2DES in Si, the glass transition occurs in the metallic phase as a precursor to the MIT.

[1] J. Jaroszyński and D. Popović, Phys. Rev. Lett. **96**, 037403 (2006).

[2] S. Bogdanovich and D. Popović, Phys. Rev. Lett. **88**, 236401 (2002); J. Jaroszyński, D. Popović, and T. M. Klapwijk, Phys. Rev. Lett. **92**, 226403 (2004).

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